| L Number | Hits | Search Text | DB | Time stamp |
|---|---|---|---|---|
| . | 1667 | 250/205;438/7,16.ccls. | USPAT; US-PGPUB; DERWENT | 2002/11/21 11:08 |
| . | 144 | (reaction NEAR4 chamber) AND (pulse NEAR3 light) AND intensity | USPAT; US-PGPUB; DERWENT | 2002/11/21 09:54 |
| . | 1 | 250/205;438/7,16.ccls. AND ((reaction NEAR4 chamber) AND (pulse NEAR3 light) AND intensity) | USPAT; US-PGPUB; DERWENT | 2002/11/21 09:56 |
| . | 46 | metrology AND 250/205;438/7,16.ccls. | USPAT; US-PGPUB; DERWENT | 2002/11/21 09:56 |
| . | 1 | (reaction ADJ chamber) AND (metrology AND 250/205;438/7,16.ccls.) | USPAT; US-PGPUB; DERWENT | 2002/11/21 10:40 |
| . | 132 | 118/691.ccls. | USPAT; US-PGPUB; DERWENT | 2002/11/21 10:42 |
| . | 19 | semiconductor AND 118/691.ccls. | USPAT; US-PGPUB; DERWENT | 2002/11/21 10:56 |
| . | 0 | pulse WITH intensity WITH cutoff AND (250/205;438/7,16.ccls. OR 118/691.ccls.) | USPAT; US-PGPUB; DERWENT | 2002/11/21 10:57 |
| . | 32 | pulse WITH intensity WITH (cutoff OR (cut ADJ off)) | USPAT; US-PGPUB; DERWENT | 2002/11/21 10:58 |
| . | 8 | light WITH pulse WITH intensity WITH (cutoff OR (cut ADJ off)) | USPAT; US-PGPUB; DERWENT | 2002/11/21 10:58 |
| . | 1019 | 250/205.ccls. | USPAT; US-PGPUB; DERWENT | 2002/11/21 11:08 |
| . | 349 | 250/205.ccls. AND pulse | USPAT; US-PGPUB; DERWENT | 2002/11/21 11:08 |
| . | 37 | (250/205.ccls. AND pulse) AND (cutoff OR (cut ADJ off)) | USPAT; US-PGPUB; DERWENT | 2002/11/21 13:02 |
| . | 6 | ((xenon OR flash) NEAR5 (lamp OR light)) AND ((250/205.ccls. AND pulse) AND (cutoff OR (cut ADJ off))) | USPAT; US-PGPUB; DERWENT | 2002/11/21 11:11 |
| . | 1 | light NEAR4 puls$4 AND ((endpoint NEAR7 detect$4) AND (semiconductor AND "reaction chamber" AND endpoint)) | USPAT; US-PGPUB; DERWENT | 2002/11/21 13:05 |
| . | 95 | (endpoint NEAR7 detect$4) AND (semiconductor AND "reaction chamber" AND endpoint) | USPAT; US-PGPUB; DERWENT | 2002/11/22 14:20 |
| . | 0 | semiconductor AND "reaction chamber" AND endpoint | JPO | 2002/11/21 13:34 |

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| 2 | ("5151595").PN. | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/21<br>16:34 |
| 21 | endpoint.ti. AND semiconductor AND "reaction chamber" | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>14:22 |
| 12 | integrat$4 AND endpoint.ti. AND semiconductor AND "reaction chamber" | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>14:26 |
| 2 | (pulse NEAR5 (light OR laser)) AND semiconductor AND "reaction chamber" AND (endpoint NEAR7 detect$4) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>14:27 |
| 9 | (US-5705808-$ or US-6231774-$ or US-6429928-$ or US-6395563-$ or US-5969805-$ or US-5151584-$ or US-5969335-$ or US-5285058-$).did. or (US-20010009459-$).did. | USPAT;<br>US-PGPUB | 2002/11/22<br>15:21 |
| 0 | ("(etching OR deposition OR semiconductor) AND (light NEAR7 external) AND (pulse)").PN. | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>15:24 |
| 0 | ("(etching OR deposition OR semiconductor) AND (light NEAR7 external)").PN. | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>15:24 |
| 8104 | (etching OR deposition OR semiconductor) AND (light NEAR7 external) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>15:24 |
| 2551 | (etching OR deposition OR semiconductor) AND (light NEAR7 external) AND (pulse) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>15:25 |
| 6 | (endpoint NEAR7 detect$4) AND ((etching OR deposition OR semiconductor) AND (light NEAR7 external) AND (pulse)) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>15:25 |
| 47 | "reaction chamber" AND ((etching OR deposition OR semiconductor) AND (light NEAR7 external) AND (pulse)) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/22<br>15:26 |
| 97 | semiconductor AND pulse AND light AND manufacture | EPO; JPO | 2002/11/25<br>10:33 |
| 10 | grimbergen.in. | USPAT;<br>US-PGPUB | 2002/11/25<br>11:46 |
| 13 | (light ADJ detector) WITH (filter ADJ element) | USPAT;<br>US-PGPUB | 2002/11/25<br>11:47 |
| 4355 | light AND detector AND feedback AND (cutoff OR cut ADJ off) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/25<br>14:12 |
| 214 | (intensity SAME integrated) AND (light AND detector AND feedback AND (cutoff OR cut ADJ off)) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/25<br>14:12 |
| 148 | pulse AND ((intensity SAME integrated) AND (light AND detector AND feedback AND (cutoff OR cut ADJ off))) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/25<br>14:12 |
| 85 | capacitor AND (pulse AND ((intensity SAME integrated) AND (light AND detector AND feedback AND (cutoff OR cut ADJ off)))) | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/25<br>15:50 |

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| 0 | 5705808.URPN. | USPAT | 2002/11/25 14:19 |
| 7 | ("3033988" \| "3350604" \| "3648104" \| "3684917" \| "4249109" \| "5134273" \| "5151595").PN. | USPAT | 2002/11/25 14:19 |
| 1372 | light WITH (power OR current OR energy) WITH (cut ADJ off OR cutoff) | USPAT; US-PGPUB; DERWENT | 2002/11/25 15:51 |
| 30 | (light WITH (power OR current OR energy) WITH (cut ADJ off OR cutoff)) SAME integrate$2 | USPAT; US-PGPUB; DERWENT | 2002/11/25 15:51 |
| 4 | (("6060397") or ("6122042")).PN. | USPAT; US-PGPUB; DERWENT | 2002/11/26 16:26 |
| 154 | semiconductor AND "reaction chamber" AND endpoint | USPAT; US-PGPUB; DERWENT | 2002/11/26 16:44 |
| 75 | intensity AND (semiconductor AND "reaction chamber" AND endpoint) | USPAT; US-PGPUB; DERWENT | 2002/11/26 16:32 |
| 14 | pulse AND (intensity AND (semiconductor AND "reaction chamber" AND endpoint)) | USPAT; US-PGPUB; DERWENT | 2002/11/26 16:33 |
| 346 | semiconductor AND "reaction chamber" AND (endpoint OR end ADJ point) | USPAT; US-PGPUB; DERWENT | 2002/11/26 16:45 |
| 150 | intensity AND (semiconductor AND "reaction chamber" AND (endpoint OR end ADJ point)) | USPAT; US-PGPUB; DERWENT | 2002/11/26 16:45 |
| 34 | pulse AND (intensity AND (semiconductor AND "reaction chamber" AND (endpoint OR end ADJ point))) | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:04 |
| 9287 | (feedback OR cutoff OR cut ADJ off OR intensity ADJ control) AND (endpoint OR end ADJ point) | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:06 |
| 9287 | (feedback OR (cutoff OR cut ADJ off) OR (intensity ADJ control)) AND (endpoint OR end ADJ point) | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:07 |
| 533 | (semiconductor NEAR7 (manufacture OR process)) AND ((feedback OR (cutoff OR cut ADJ off) OR (intensity ADJ control)) AND (endpoint OR end ADJ point)) | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:08 |
| 128 | (light NEAR7 intensity) AND ((semiconductor NEAR7 (manufacture OR process)) AND ((feedback OR (cutoff OR cut ADJ off) OR (intensity ADJ control)) AND (endpoint OR end ADJ point))) | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:35 |
| 3492 | capacitor WITH laser | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:35 |
| 1112 | pulse SAME (capacitor WITH laser) | USPAT; US-PGPUB; DERWENT | 2002/11/26 17:35 |

| 3386 | 250/205,206;438/7,14,16,17.ccls. | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/27<br>11:00 |
| 381 | pulse AND intensity AND<br>250/205,206;438/7,14,16,17.ccls. | USPAT;<br>US-PGPUB;<br>DERWENT | 2002/11/27<br>11:00 |